Silicon Epitaxial Planar Diode for High Voltage Switching

## **HITACHI**

ADE-208-843(Z) Rev 0 Mar 2000

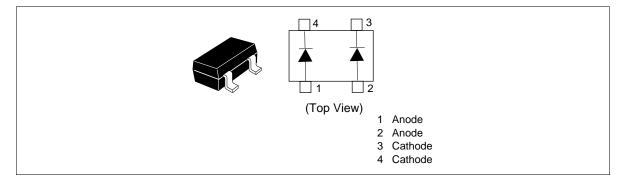
#### **Features**

- High reverse voltage. (V<sub>R</sub>=250V)
- CMPAK- 4 package which has two devices parallel connection, is suitable for high density surface mounting.

#### **Ordering Information**

Type No.	Laser Mark	Package Code
HSB83YP	F7	CMPAK-4

#### **Outline**





## Absolute Maximum Ratings (Ta = 25°C) \*2

Item	Symbol	Value	Unit
Peak reverse voltage	$V_{RM}$	300	V
Reverse voltage	$V_R$	250	V
Peak forward current	$I_{FM}$	300	mA
Non-Repetitive peak forward surge current	I <sub>FSM</sub> *1	2	A
Average rectified current	I <sub>o</sub>	100	mA
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55Å`+125	°C

Note 1. Value at duration of 10msec.

Note 2. Two device total.

### Electrical Characteristics (Ta = $25^{\circ}$ C) \*<sup>1</sup>

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V <sub>F</sub>	_	_	1.2	V	I <sub>F</sub> = 100 mA
Reverse current	I <sub>R1</sub>	_	_	0.2	μΑ	V <sub>R</sub> = 250V
	I <sub>R2</sub>	_	-	100	<del></del>	V <sub>R</sub> = 300V
Capacitance	С	-	_	3.0	pF	$V_R = 0V, f = 1 MHz$
Reverse recovery time	t <sub>rr</sub>	_	-	100	ns	$I_F = I_R = 30 \text{ mA}, I_{rr} = 3\text{mA}, R_L = 100\Omega$

Note 1. Per one device.

### **Main Characteristic**

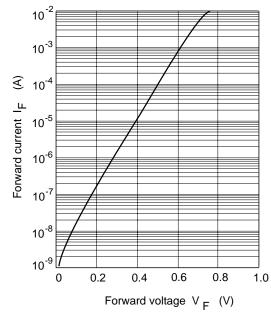
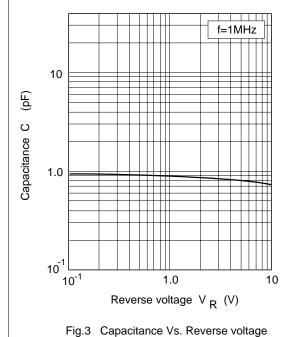


Fig.1 Forward current Vs. Forward voltage

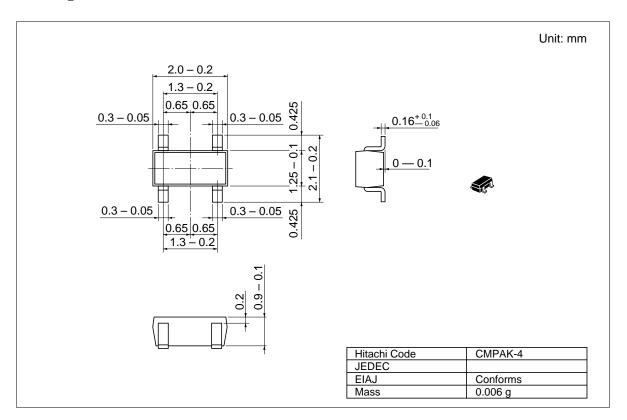


10<sup>-5</sup>

Reverse voltage V<sub>R</sub> (V)

Fig.2 Reverse current Vs. Reverse voltage

### **Package Dimensions**



#### **Cautions**

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